

Application of photonic crystals to gas analysis

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Aim

Exploitation of enhanced absorption in photonic crystals for detection of gases

Idea

If the absorption frequency of a gas filled into the pores of a macroporous Si photonic crystal is close to upper edge of the first band gap, two properties of light propagation through a photonic crystal can be exploited:

- Low group velocity near band edge results in an effective prolonged propagation time, i.e. enhanced interaction time of light with the gas
- Concentration of electromagnetic field of light in the gas-filled pores (air band)

→ 2001 - 2003 : Macroporous Si 3D PBGs as model system
→ 2003 - 2005 : Macroporous Si 2D PBGs as realistic system

Team

IPM: Dr. A. Lambrecht, Dr. A. Feist, P. Hahn (partly DFG-funded 2001), R. Glatthaar (partly DFG-funded 2002)

MPI: Dr. R. B. Wehrspohn, Dr. S. Schweizer, C. Jamois, Dr. J. Schilling, S. Matthias, T. Geppert, TA Andreas Herbst (partly DFG-funded)

Scientific Output

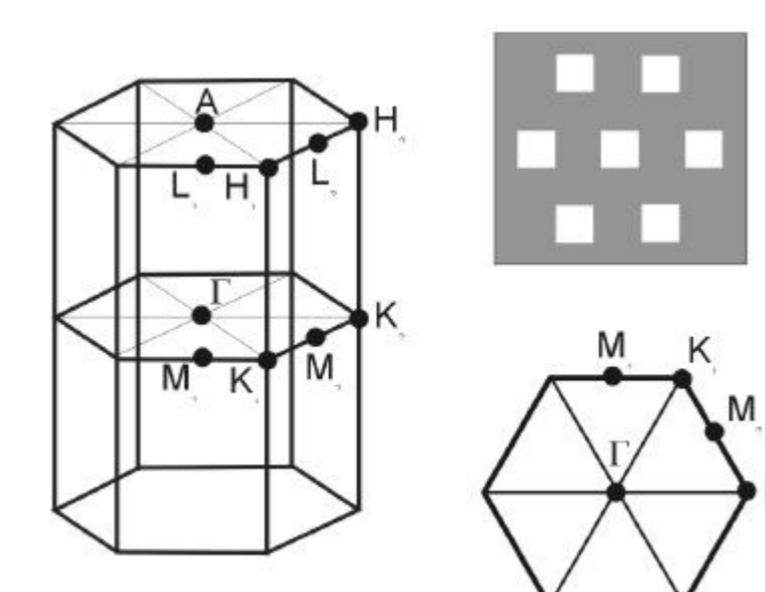
Patent: "Vorrichtung und Verfahren zur Analyse der qualitativen und / oder quantitativen Zusammensetzung von Fluiden", 10063151.7 (Aktenzeichen Dt. Patentamt) bzw. PCT/EP01/14802 (PCT-Nummer)

Publications: J. Schilling et al., Mater. Res. Soc. Proc. 722, L6.8 (2002)

Talks: La Roche Diagnostic internal seminar (2001), Dräger AG internal seminar (2002), EH Conducta AG internal seminar (2002)

Optical properties of 3D-macroporous silicon photonic crystals

Crystal properties

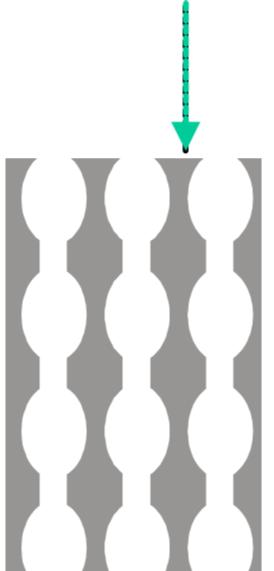
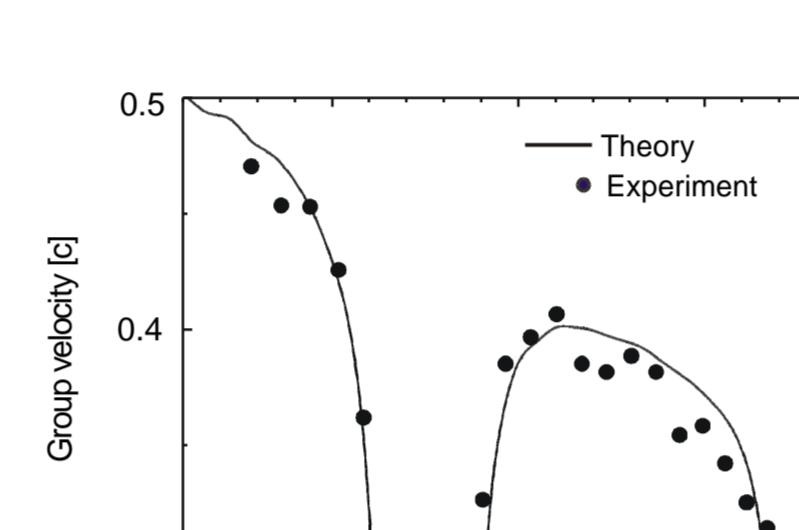
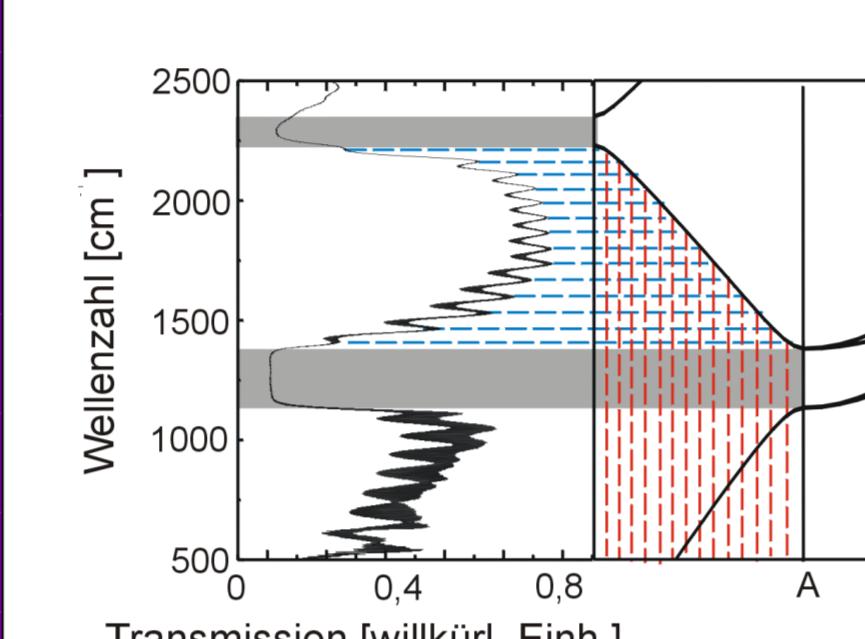


3D-crystal symmetry:
base-centered orthorhombic

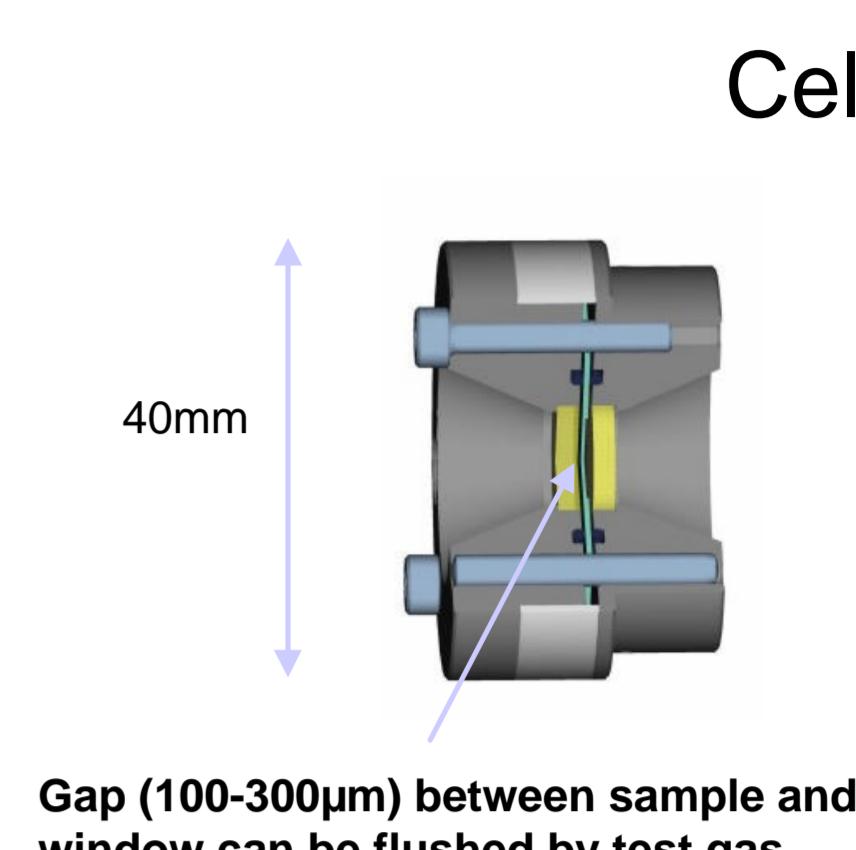
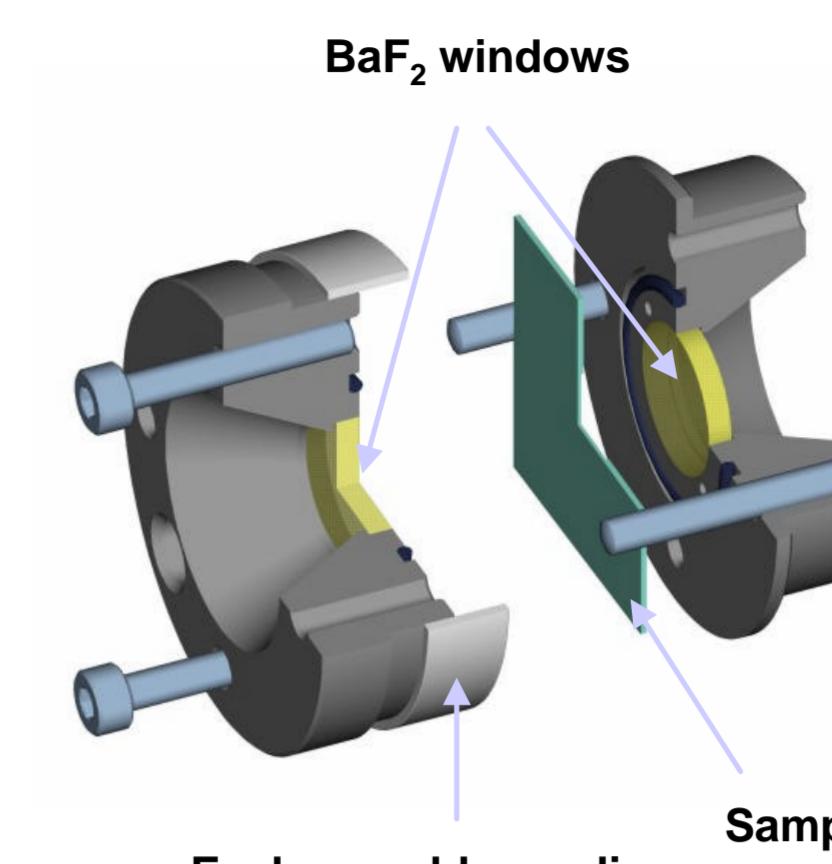
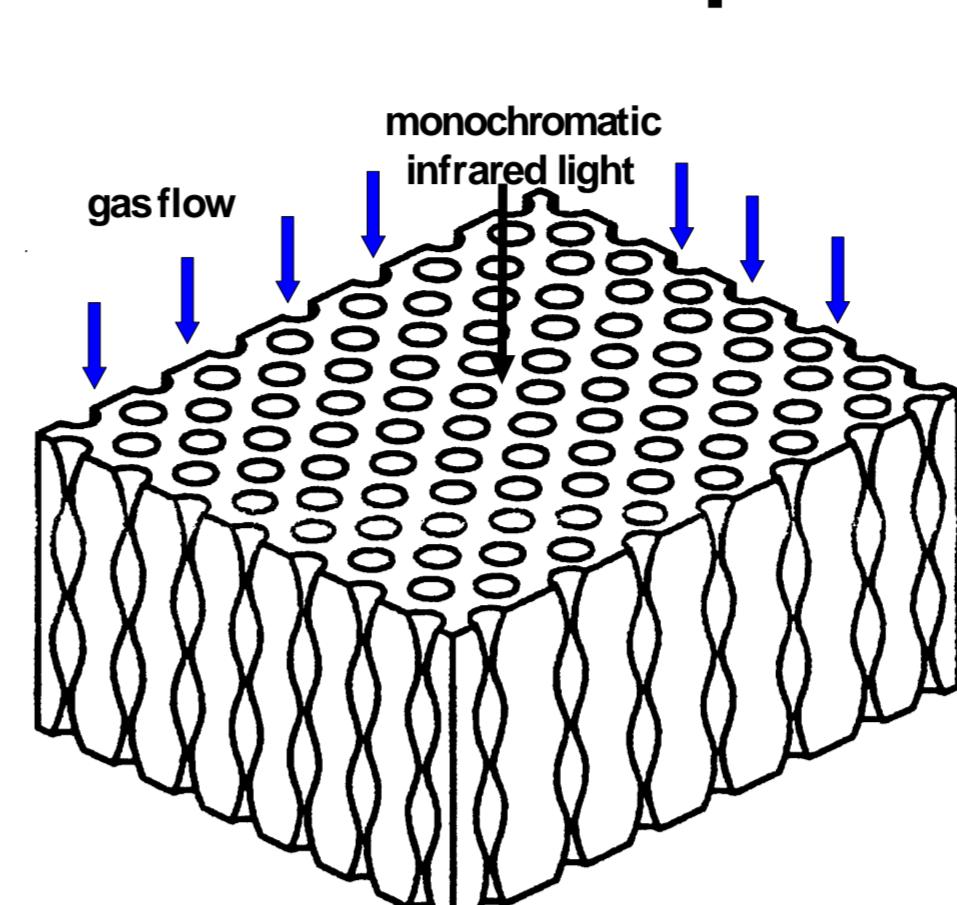
Properties:

- No complete 3D band gap, but stop-gaps in all 3 directions
- Polarization dependent band gap

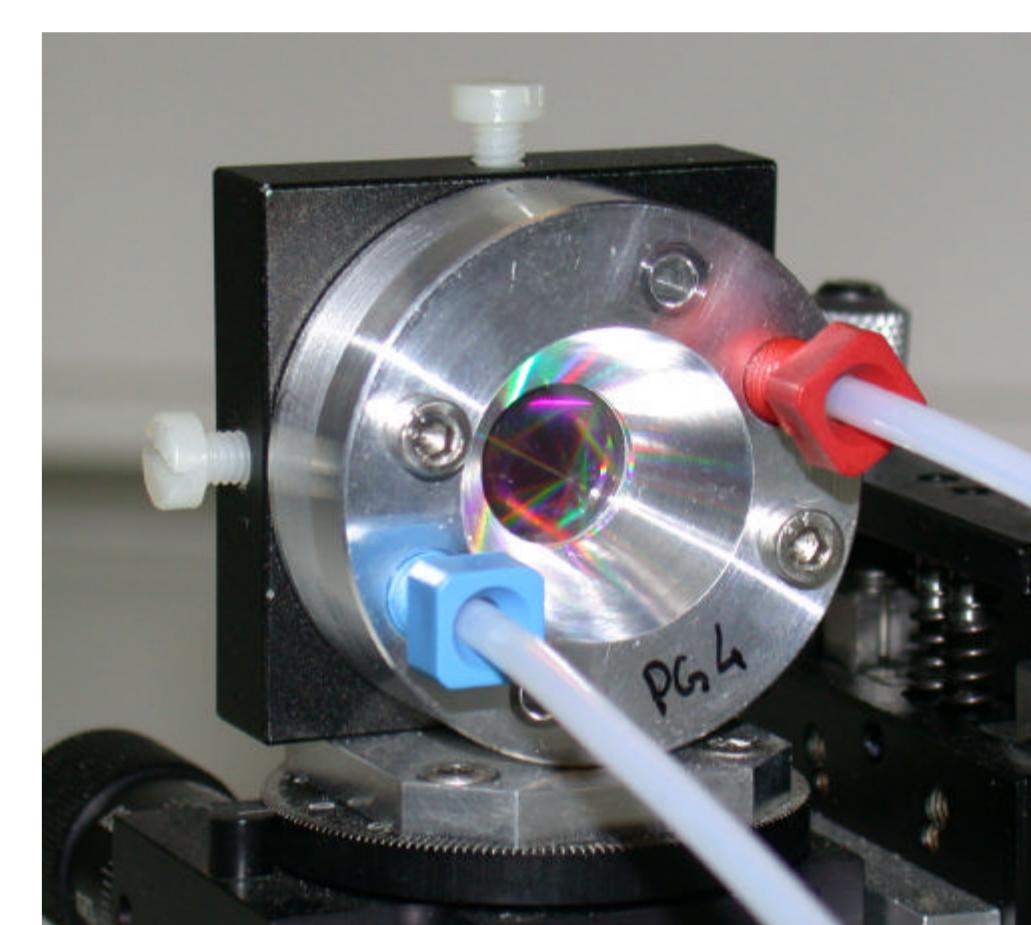
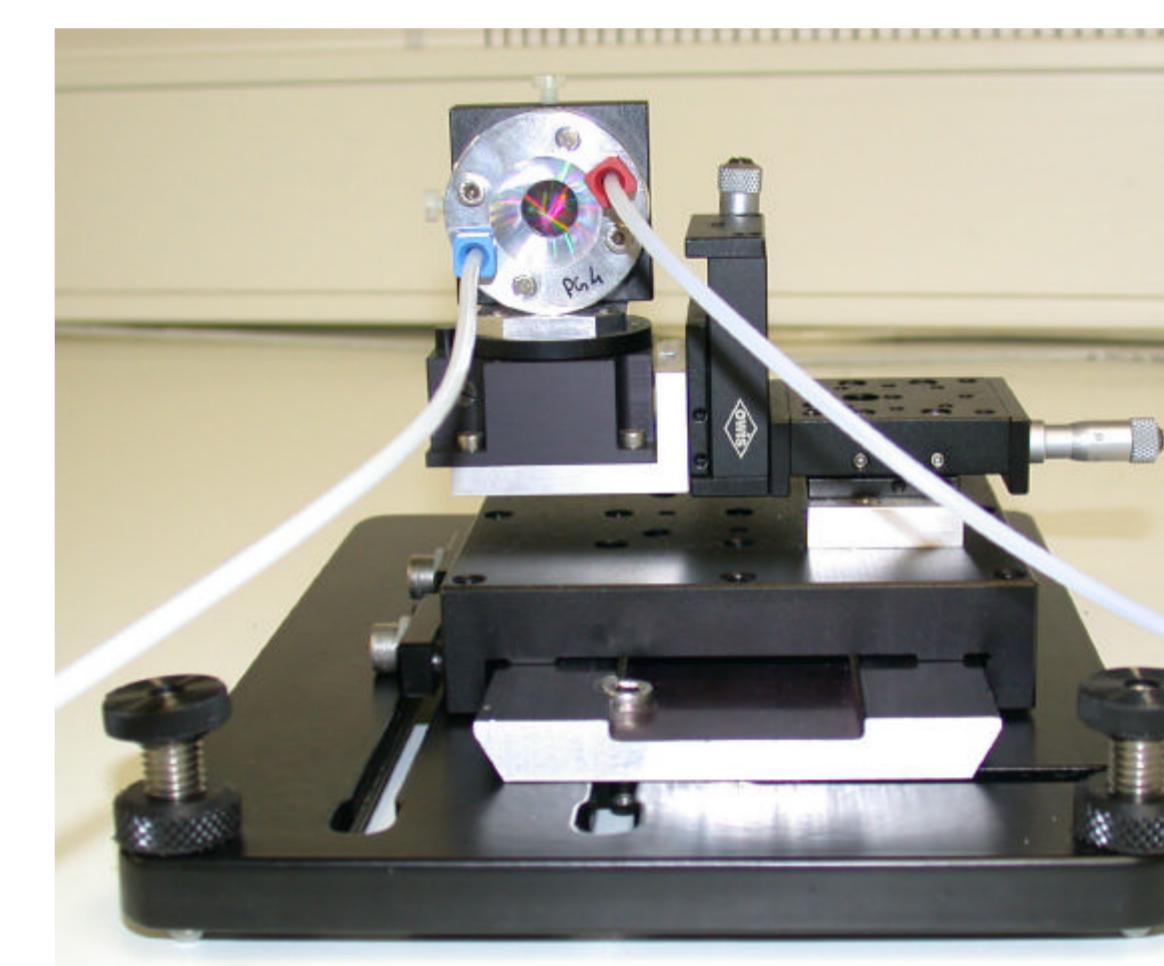
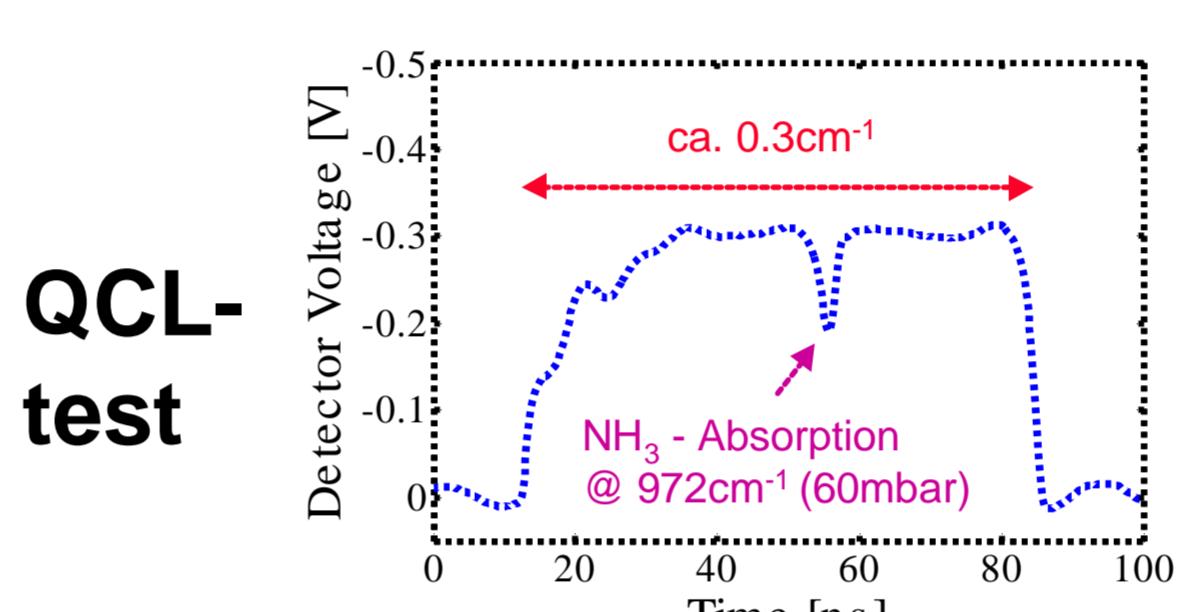
Optical properties in G-A direction



Measurement setup



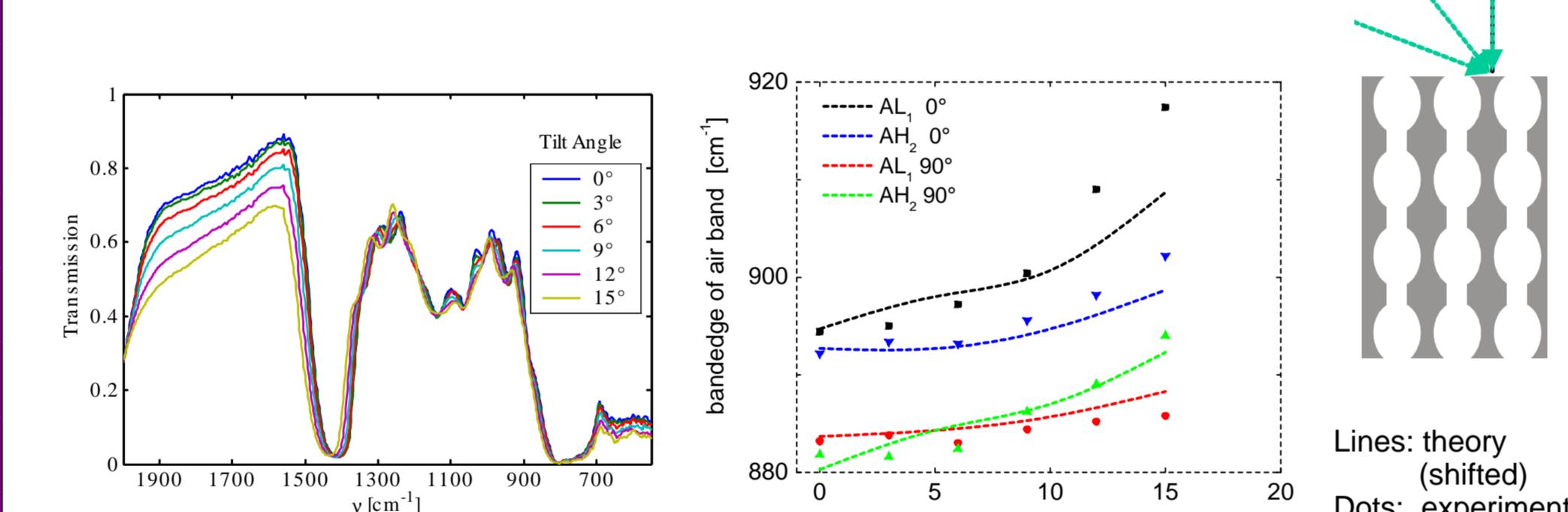
Optical measurements
in Bruker IFS 66 v/S. In future
with Quantum Cascade Laser



For 15 modulation periods, $v_g = c/3$ is optically determined.

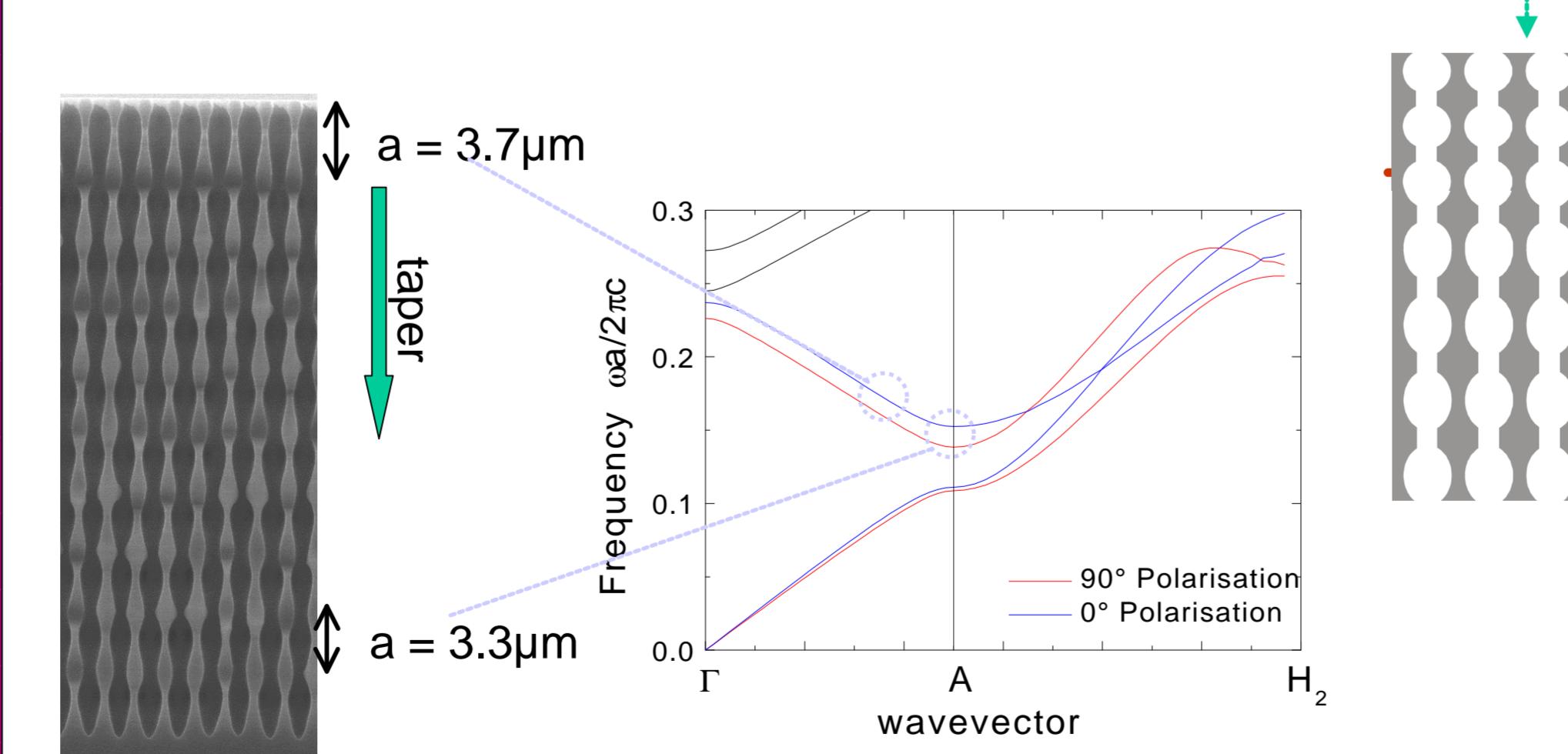
J. Schilling et al., Mater. Res. Soc. Proc. 722, L6.8 (2002)

Band edge tuning by tilting



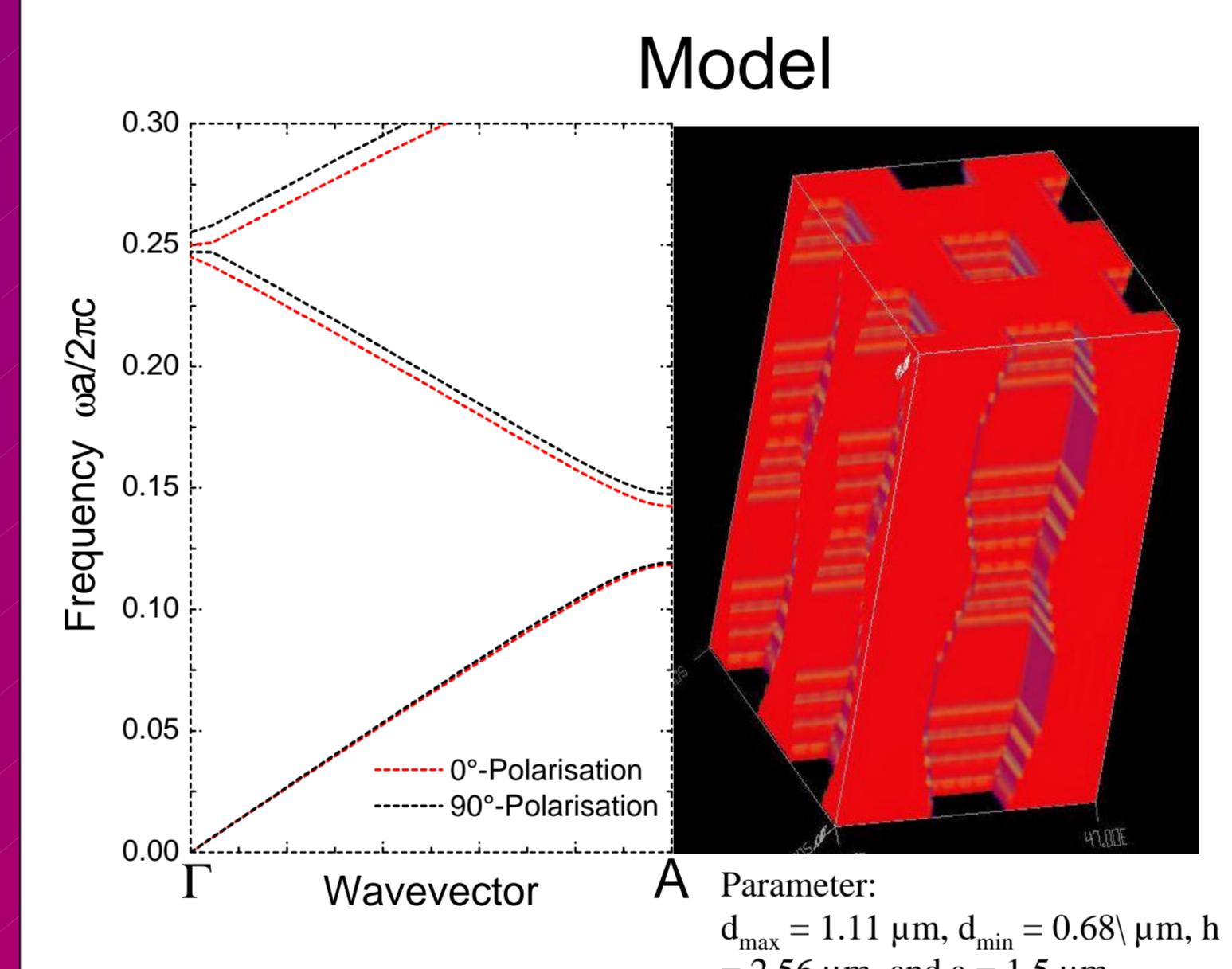
The easiest way to tune the 3D-crystal is by tilting. An absolute shift of 35 cm⁻¹ is observed. This corresponds to a relative band edge shift of 3.5% and can compensate for fabrication tolerances which are in the range of a few percent for the optimized process.

Tapering

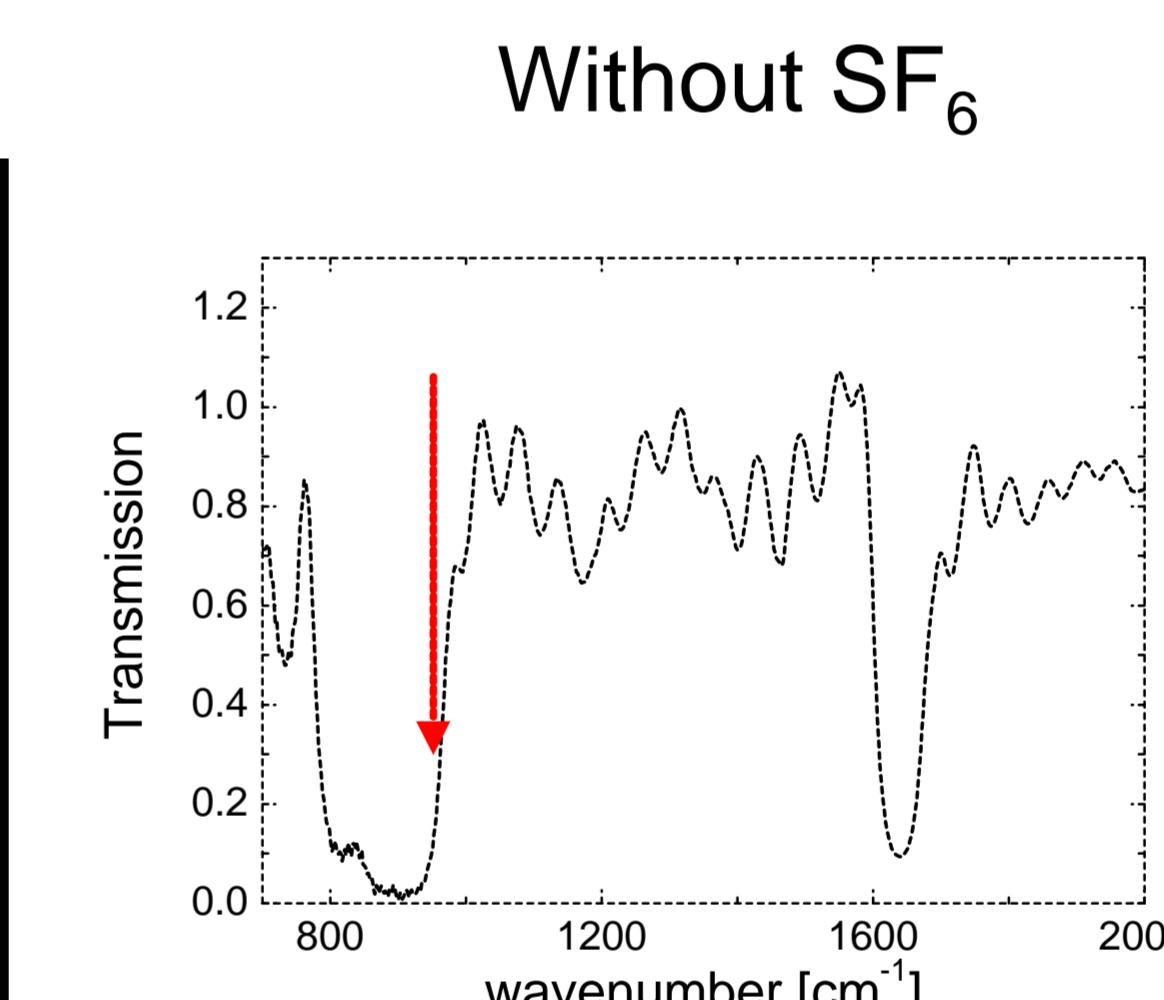


Tapering / Chirping allows to couple to low- v_g bands, variation of the modulation period with depth can be easily realized by designing an appropriate illumination profile.

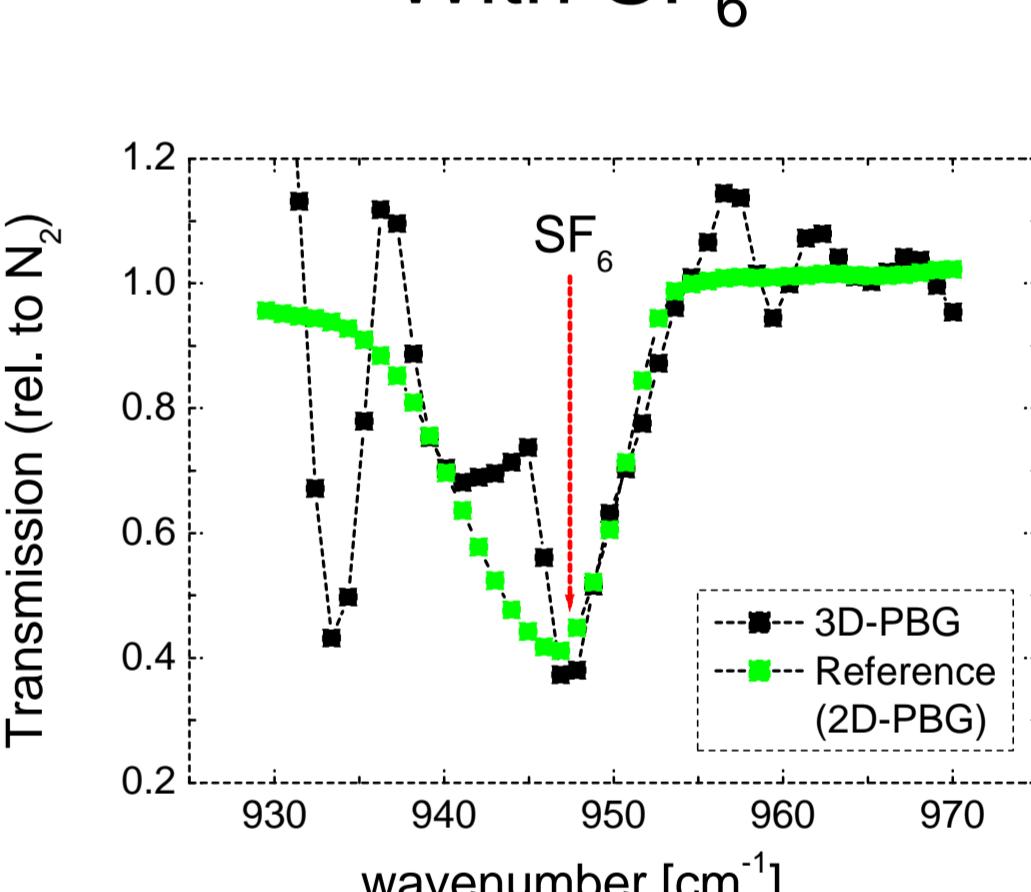
First optical measurements of 3D-PBG with SF₆ (@948 cm⁻¹)



Model



Without SF₆

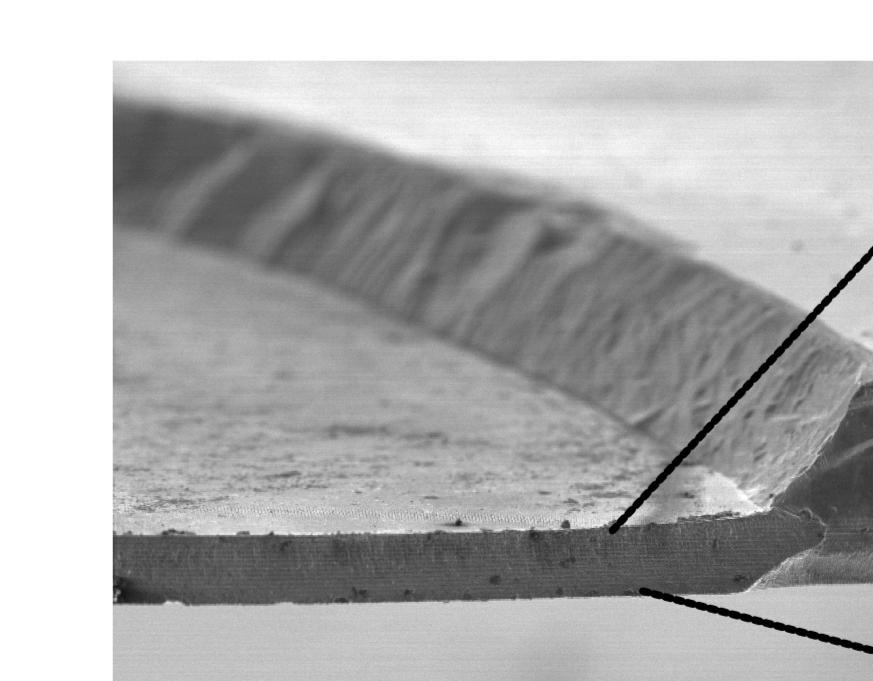
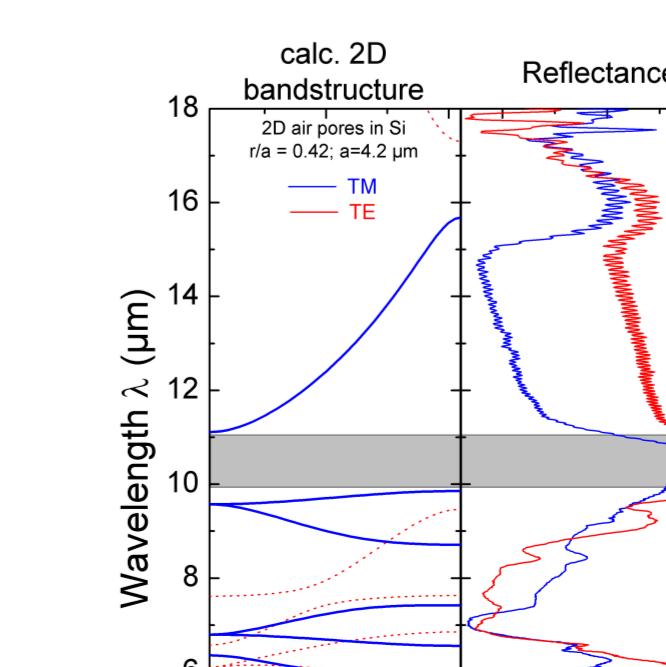
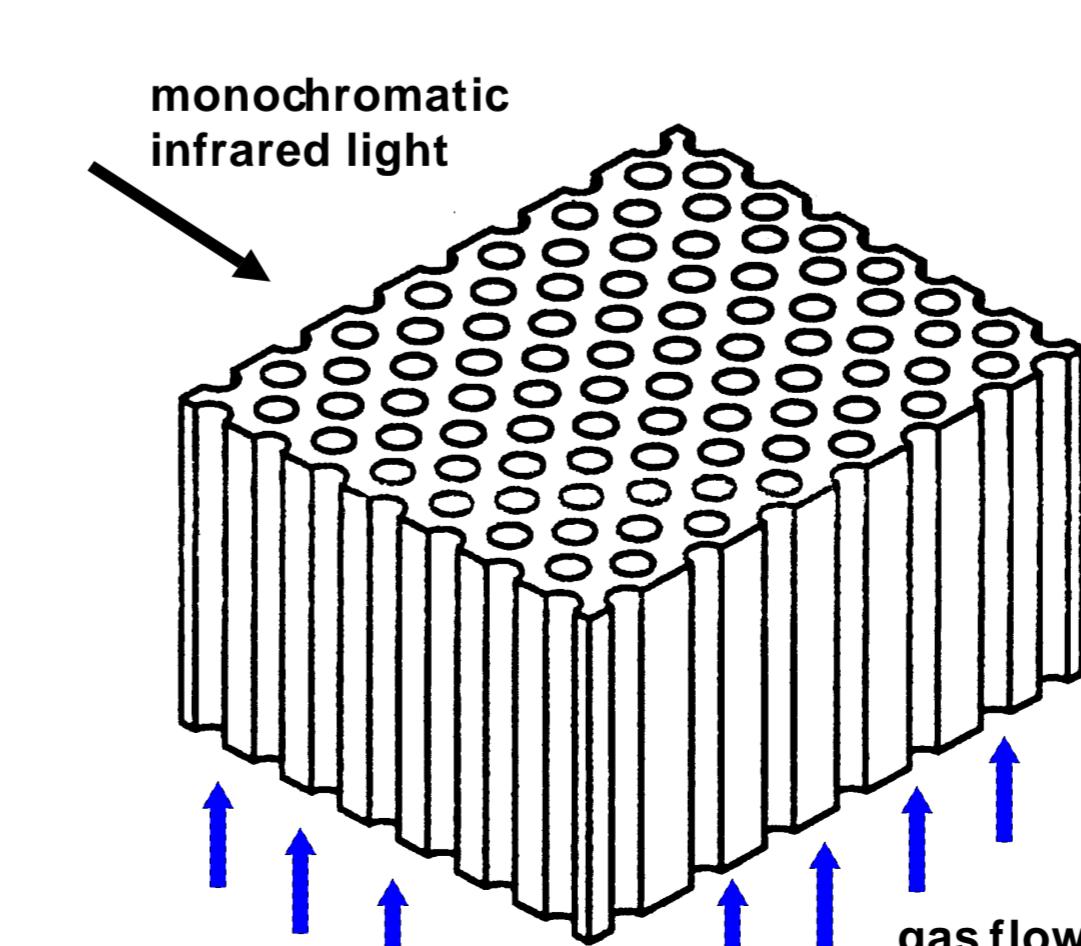


With SF₆

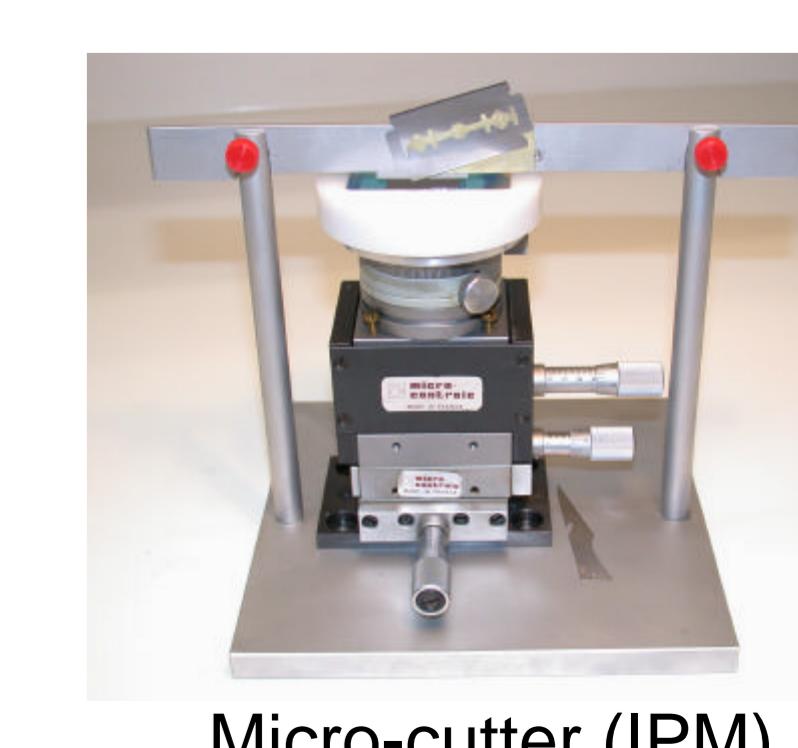
Absorption of SF₆ in 3D-PBG clearly observable! However, due to low coupling efficiency and small number of modulation periods, no enhancement observable.
Next step: Taper + 30-40 modulation periods.

Work ahead (2003-2005)

- Verification of enhanced absorption
- Change to 2D-PCs with air band edge at 948 cm⁻¹.



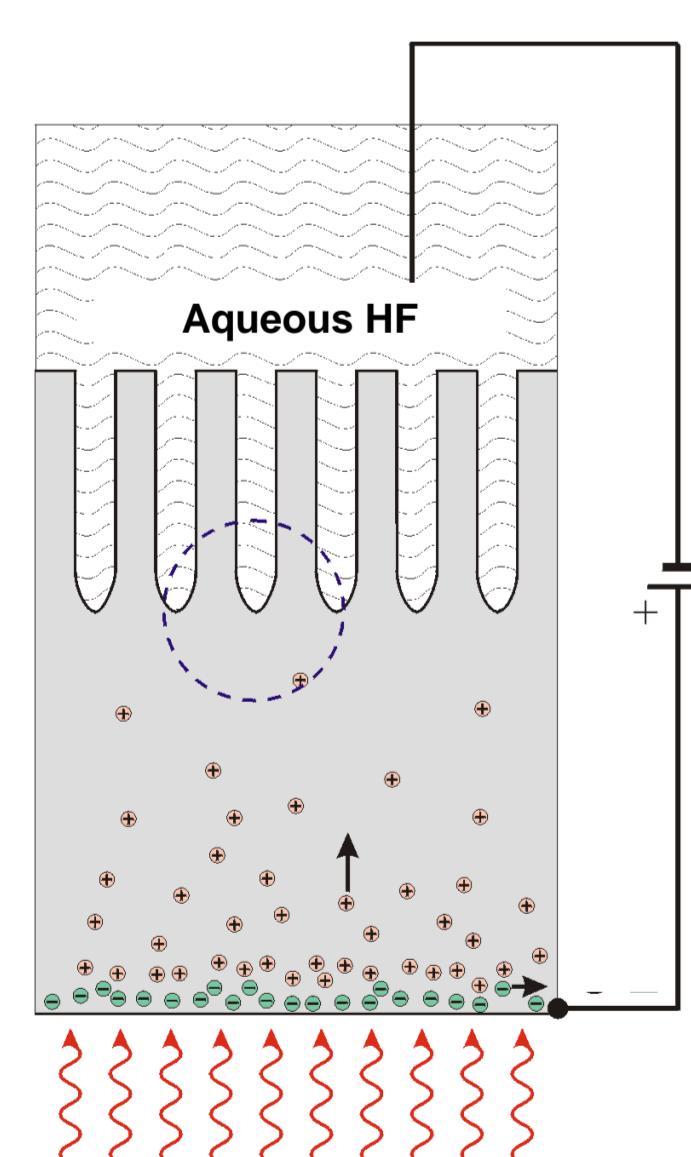
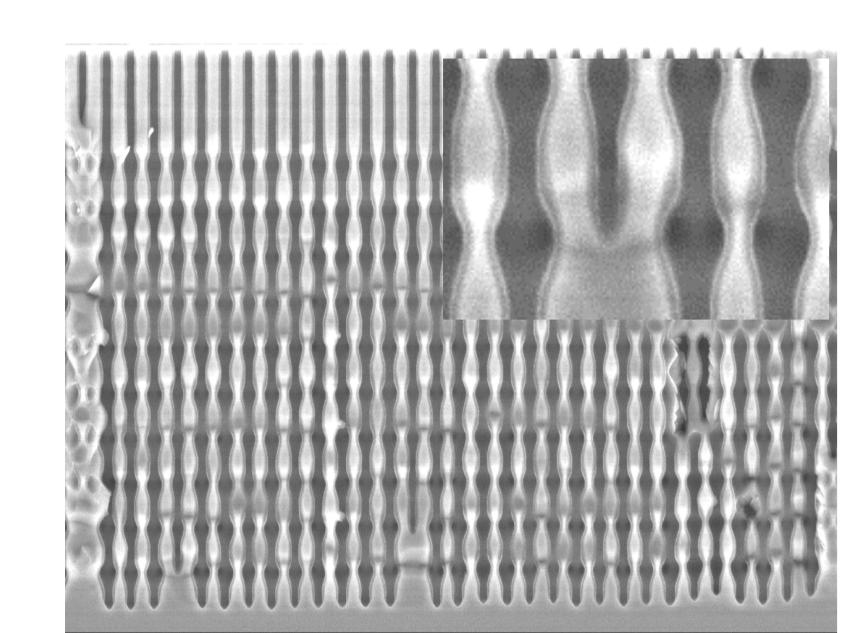
First realizations with $a = 4.2 \mu\text{m}$



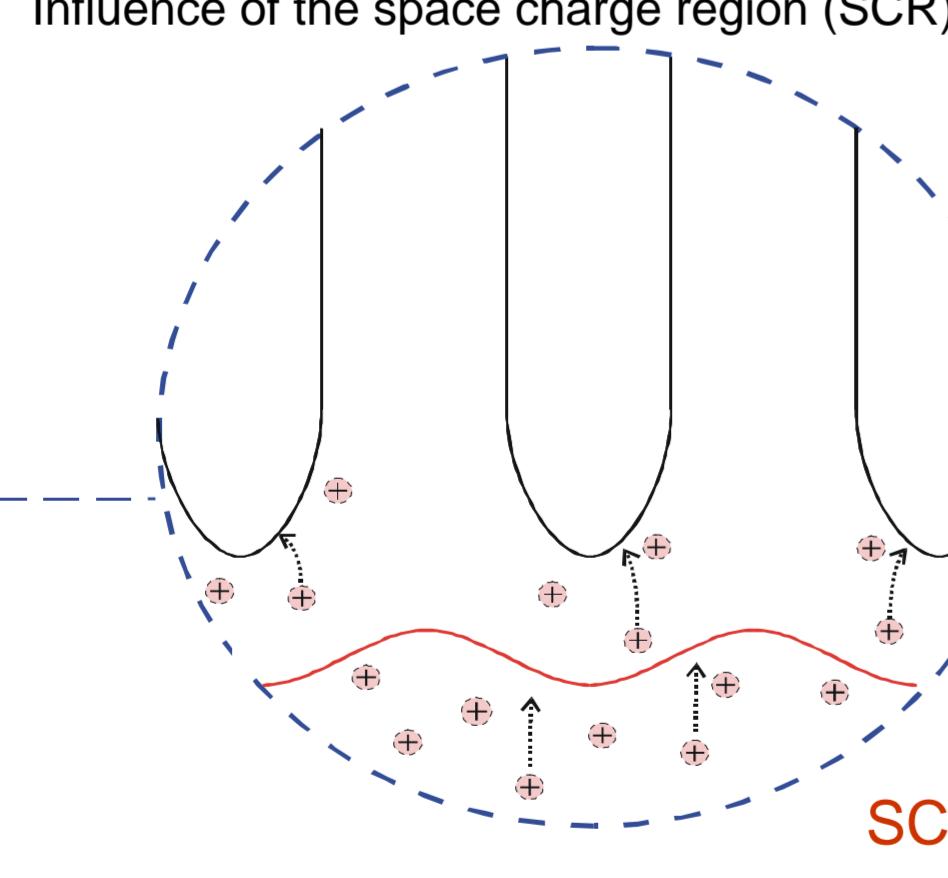
First optical characterizations, the band gap is clearly observable

Modulated macropores - Fabrications issues

Problems encountered:
Pores die or merge during high-carrier concentration pulse.



Influence of the space charge region (SCR)



$$V_{\text{etch}} \sim kT C^{3/2}$$

Reason: Focusing effect of the SCR is reduced during high-carrier concentration pulse

Solution: Increase of etching velocity
- increase of T
- increase of HF concentration
Higher-quality samples achieved

